

MASTR Progress Line

132-174 MHZ, 80-WATT TRANSMITTER MODEL 4ET58A30-41 & 4ET58B10-15



SPECIFICATIONS

FCC filing Designation:

Frequency Range:

Power Output:

Crystal Multiplication Factor:

Frequency Stability:

Spurious & Harmonic Radiation:

Modulation:

Audio Frequency Characteristics:

Distortion:

Deviation Symmetry: Narrow Band -Wide Band

Tubes & Transistors:

Maximum Frequency Spacing

Duty Cycle:

Mobile -

Station -

ET-58-A (Narrow Band) ET-58-B (Wide Band)

132 - 174 MHz

80 watts minimum

12

 $\pm .0005\%$ (-30°C to +60°C)

At least 85 dB below rated power output

Adjustable from 0 to ±5 KHz (Narrow Band) and 0 to ±15 KHz (Wide Band) swing with instantaneous modulation limiting

Within +1 dB to -3 dB of a 6 dB/octave preemphasis from 300 to 3000 Hz per EIA standards. Post limiter filter per FCC and EIA

Less than 5%

0.5 KHz maximum 1.5 KHz maximum

80-watt Transmitter with no Options:

8 transistors

4 diodes

0.4%

20% transmit (one minute transmit, four minutes off)

Continuous

*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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WARNING ---

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

DESCRIPTION

The MASTR Progress Line FM Transmitter Types ET-58-A and B are crystal-controlled, phase-modulated transmitters designed for one-, two-, or four-frequency operation within the 132-174 megahertz band. The transmitter consists of the following modules:

- Transistorized Exciter Board, with audio, oscillator, modulator, amplifier and multiplier stages,
- Tubed multipliers and power amplifier stages,
- Optional transistorized Channel Guard Board. (ET-58-A only)

All input leads to the transmitter are individually filtered by the 20-pin feed-through by-pass connector J101. The output passes through a four-section, low-pass filter that features good shielding between sections, and Teflon® capacitors for fail-free operation with an open or shorted antenna.

CIRCUIT ANALYSIS

Eight silicon transistors and only three tubes are used in the transmitter. The frequency of the crystals used ranges from 11 to 14.5 megahertz, and the crystal frequency is multiplied twelve times.

A centralized metering jack (J102) is provided for use with General Electric Test Set 4EX3A10. The Test Set meters the multiplier, amplifier and PA stages as well as filament and regulated supply voltages. The metering jack also provides access to receiver audio, microphone and push-to-talk leads.

POWER INPUTS

The following supply voltages are connected from the power supply to the transmitter through the 20-pin by-pass connector J101:

- Pin 3 Filament voltage
- Pin 4 +300 volts MULT B+
- Pin 5 -- +650 volts PA B+
- Pin 8 -45 volts bias
- Pin 14 +10 volts for Channel Guard option (ET-58-A only)
- Pin 15 -20 volts for Exciter Board

OSCILLATOR

A transistorized Colpitts oscillator (Q3) is used in the transmitter. The oscillator crystal is thermistor-compensated at both ends of the temperature range to provide instant frequency compensation, with a frequency stability of $\pm 0.0005\%$ without

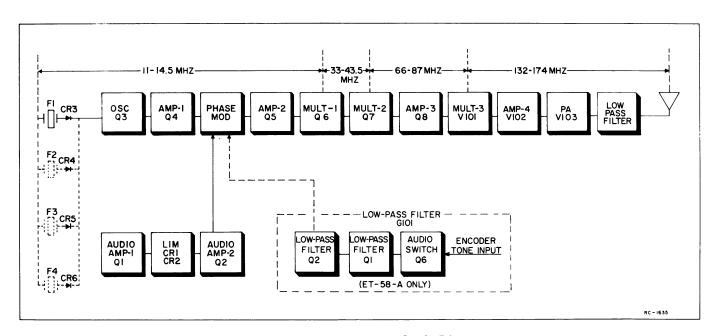


Figure 1 - Transmitter Block Diagram

crystal ovens or warmers.

In single-frequency transmitters, a jumper (from H1 to H2) connects the F1 crystal keying lead to ground to forward bias diode CR3. Forward biasing the diode reduces its impedance, and the crystal frequency is applied to the base of oscillator Q3. Feedback for the oscillator is developed across C34/C35. The oscillator output is coupled through an impedance matching emitter-follower amplifier stage (Q4) to the phase modulator.

In multi-frequency transmitters, the single oscillator transistor is used, and up to three additional crystal circuits, identical to the F1 crystal circuit, can be added. The keying jumper is removed and the proper crystal frequency is selected by switching the crystal keying lead to ground by means of a frequency selector switch on the Control Unit.

AUDIO AMPLIFIERS AND LIMITER

An audio signal from the microphone is coupled through Cl to the base of Class A audio amplifier Ql. The design of the microphone, in conjunction with C2 and R3, produces a 6-dB audio pre-emphasis. RF decoupling is provided by R10 and C75.

The amplified audio signal is RC coupled to the diode limiters, CR1 and CR2. These diodes operate in series and are normally in a forward conducting state. An audio signal of sufficient amplitude to cause limiting takes the diodes out of conduction, so that one diode conducts only on positive cycles and the other conducts only on negative cycles.

Following the limiter stage is a second Class A amplifier, Q2. The output of Q2 is coupled through MOD ADJUST potentiometer R12 to a combined post-limiter filter and de-emphasis network. This network consists of R15, R16, R17, C4, C7 and C8/C9. The output of the filter and de-emphasis network is applied directly to the phase modulator.

PHASE MODULATOR

The phase modulator uses varactor CVI (voltage variable capacitor) in series with tuneable coil L1/L2. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator varies the bias of CVI, resulting in a phase-modulated output. The output of the modulator is coupled through blocking capacitor C41/C45 to the base of the second amplifier. For Channel Guard and wide band transmitters, a second modulator stage (L3/L4 and CV2) is cascaded with the first modulator. The output of the Channel Guard encoder is fed through CHANNEL GUARD MOD ADJUST R34 to the modulator stages.

The voice audio is also applied to both modulator stages.

AMPLIFIERS AND 1st AND 2nd MULTIPLIERS

The second amplifier (Q5) isolates the modulator from the loading effects of the first multiplier and provides amplification. The output is DC coupled to the first multiplier.

Following Q5 are two inductively coupled Class C, common-emitter multiplier stages (Q6 and Q7). Q6 is a tripler, with collector tank T1 tuned to three times the crystal frequency. Metering resistor R37 is for metering the MULT-1 stage at centralized metering jack J102.

Q7 operates as a doubler stage, with collector tank T3 tuned to six times the crystal frequency. Resistor R39 is for metering the MULT-2 stage at J102. The output of Q7 is inductively coupled through T3 and T4 to amplifier Q8. In 150.8—174 megahertz transmitters, capacitor C58 provides some high-side capacitive coupling.

Third amplifier Q8 is a neutralized straight-through amplifier. Feedback through C65 from the output link on T5 provides neutralization. This stage is metered at J102-3 across R43. The output is coupled to the grid tank of multiplier V101.

3rd MULTIPLIER

The output of the transistorized Exciter is coupled by a short length of RF cable to the grid tank (Z101/Z102) of beam pentode V101. This stage operates as a doubler with the plate tank tuned to twelve times the crystal frequency. The plate tank is tuned by C106.

The grid of V101 is metered through metering resistor R102 at J102-4. R101 drops the bias voltage to approximately -18 volts to protect V101 against loss of drive. Plate voltage is supplied through L101.

When measuring grid current to V101, there will be a residual reading of approximately 0.18 volts without any drive. This is caused by the presence of fixed bias voltage to the grid of the tube.

AMPLIFIER 4

The output of the MULT-3 stage is coupled to the grid of the compactron beam power amplifier (V102) by a pi-network consisting of C106, L102/L103 and C107. The grid is metered at J102-5 through metering resistor R106. Bias voltage is supplied through R105 and L114.

When measuring the grid voltage, there will be a residual reading of approximately

0.45 volt without any drive to the stage. Neutralization is provided by Cl21. The plate tank is series-tuned by Cl11.

POWER AMPLIFIER

Drive from 4th amplifier V102 is inductively coupled to the grid power amplifier V103 through L104/L105 and L106/L107. For large changes in frequency (over ±0.2%), the physical spacing between the two coils must be adjusted by bending L104/L105. The coil should be adjusted for maximum coupling for the high end of the frequency range, and for minimum coupling for the low end of the frequency range.

The PA grid is metered at J102-6 through metering resistors R3 and R5. Bias voltage is applied to the control grids through R3 and R4.

Power amplifier V103 is a dual tetrode operating in a push-pull circuit. The PA plate is parallel-tuned by "butterfly" capacitor C112. High B-plus is applied through L113 to a center tap on the plate tank coil, L108/L109. C113 is a mechanical high-voltage by-pass capacitor.

The screen grid dropping resistors are R7 and R8. Plate current is metered from J102-1 to J102-9 across metering resistor R108.

-WARNING-

The meter leads are at plate potential (high B-plus) when metering the PA plate.

Placing the TUNE-OPERATE switch (S102) in the OPERATE position applies 300 volts to Al19-J8 and -J10. The 300 volts appearing on each side of R8 effectively shorts the resistor out of the circuit, and the screen voltage is applied through R7 for normal operation of V102. With S102 in the TUNE position, the screen voltage is applied to Al19-J8 only. Now, dropping resistors R7 and R8 are in series, to reduce the screen voltage. This reduces the plate dissipation of V103 while tuning the power amplifier stage.

Antenna coupling is achieved by varying the coupling between L108/L109 and L110/L111. C114 tunes the antenna circuit.

The RF output from the antenna coil is fed to low-pass filter FL101. This filter has a low insertion loss and a harmonic attenuation of at least -50 dB through all harmonics. The filter output is fed to the antenna changeover relay located on the front of the system frame.

CHANNEL GUARD

Low Pass Filter (G101)

In encode-decode combinations, low-pass filter G101 is assembled on a printed wiring

board that mounts on the underside of the MASTR transmitters. The filter is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied continuously (even in the STANDBY position), and the -20 volts is applied only when the transmitter is keyed.

Keying the transmitter applies the encoder tone (from the receiver) to low-pass filter GlO1. Transistors Ql and Q2 form a two-section, active low-pass filter that reduces tone distortion and power supply ripple. Q6 operates as a tone switch, applying the tone input to the filter whenever +10 volts is applied to J1 (Q6 base). Thermistor RT1 keeps the output constant over wide variations in temperature. The filter output is coupled to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or be removing the microphone or handset from the operational hang-up bracket.

-NOTE-

When Channel Guard decode only is desired, remove the wire that connects to J6 on the low-pass filter (Encoder Tone Input).

Encoder Model 4EH17A10 (Optional)

In encode only combinations, encoder Model 4EH17A10 mounts on the underside of the MASTR transmitter. The encoder is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied to Q3, Q4 and Q5 continuously (even in the STANDBY position). The -20 volts is applied to Q1 and Q2 only when the transmitter is keyed.

The encoder tone is provided by selective oscillators Q3 and Q4, which oscillate continuously at a frequency determined by the tone network (FL1). Negative feedback, applied through the tone network to the base of Q3, prevents any gain in the stage except at the desired encode frequency.

Thermistor-resistor combination R14 and RT2 provides temperature compensation for the oscillator output. Limiter diodes CR1 and CR2 keep the tone amplitude constant.

Keying the transmitter applies -20 volts to the two-stage, active low-pass filter (Q1 and Q2) turning them on. The oscillator output is then coupled through emitter-follower Q5 to the low-pass filter. Thermistor RTl keeps the filter output constant over wide variations in temperatures.

The output of the filter is applied to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the operational hang-up bracket.

REDUCED POWER OPERATION

STATION APPLICATIONS

Station power supply Model 4EP38A10 may be modified to operate at reduced power. Select one of the modifications ("A" thru "D") shown in the chart at the bottom of this page that meets the desired power limitations.

Transmitter Alignment Procedure

Tune the transmitter according to the standard Alignment procedure, but adjust the ANT COUPLING control by one of the two following methods:

CAUTION -- Do not allow the PA PLATE reading to exceed 0.7 volts.

- Method 1 Measure the power output directly, using an RF wattmeter, and adjust the ANT COUPLING control for the required power output.
- Method 2 The efficiency of the power amplifier is in modified transmitter will vary from about 47% to 60%. Use the highest anticipated efficiency (60%) and adjust

the ANT COUPLING control for the following PA PLATE reading:

"PA PLATE" reading = $\frac{3 \text{ x desired power}}{\underset{\text{efficiency x PA}}{\text{output}}}$

Follow the standard transmitter Alignment Procedure for measuring the PA PLATE voltage.

MOBILE APPLICATIONS

The mobile transmitter with power supply Model 4EP37A10 power supply may be operated at reduced power (120-watt plate input limitation) as required by Part 93 (Land Transportation Radio Services) and Part 21 (Domestic Public Radio Services) of FCC rules by using the following procedure.

Power Supply Modification*

Move the jumper in the secondary of transformer T501 from T501-23 to T501-22. This modification provides a typical plate voltage of 550 volts.

Transmitter Alignment Procedure

Tune the transmitter according to the standard Alignment Procedure for maximum power output while maintaining 120 watts input to the PA. Refer to the PA POWER INPUT instructions on the transmitter Alignment Procedure to determine the PA input.

*If Option 7041 is ordered, the power supply will be modified before shipment from the factory.

	PA POWER OUTPUT LIMIT	MODIFICATION OF POWER SUPPLY	TYPICAL PA PLATE VOLTAGE	MAX. PA PLATE POWER INPUT	MAX. EFFI- CIENCY
A *	65 watts	Interchange white wire at TB8-3 and green wire at H4 (on board A501).	467 VDC	109 watts	60%
В	40-58 watts	a) Remove jumper from TB8-4 to TB8-5. b) Add jumper from TB8-3 to TB8-5. c) Remove jumper from TB7-3 to TB7-4. d) Add jumper from TB7-2 to TB7-3.	415-435 VDC	101 watts	60%
С	35-40 watts	Remove fuse F502.	297-300 VDC	70 watts	60%
D	30-38 watts	a) Remove fuse F502. b) Remove jumper from TB7-3 to TB7-4. c) Add jumper from TB7-2 to TB7-3.	275-280 VDC	65 watts	60%

^{*} Modification "A" is required for operation under Part 93 (Land Transportation Radio Services) of FCC rules. If Option 7044 is ordered, the power supply will be modified before shipment from the factory.

MAINTENANCE

DISASSEMBLY

To service the transmitter from the top -

- 1. Pull locking handle down and pull radio about one inch out of mounting frame.
- 2. Pry up cover at rear of transmitter.
- 3. Slide cover back and lift off.

To service the transmitter from the bottom-

- Pull locking handle down and pull radio out of mounting frame.
- 2. Remove the two screws in the bottom cover, and pry up at back of transmitter.
- 3. Slide cover back and lift off.

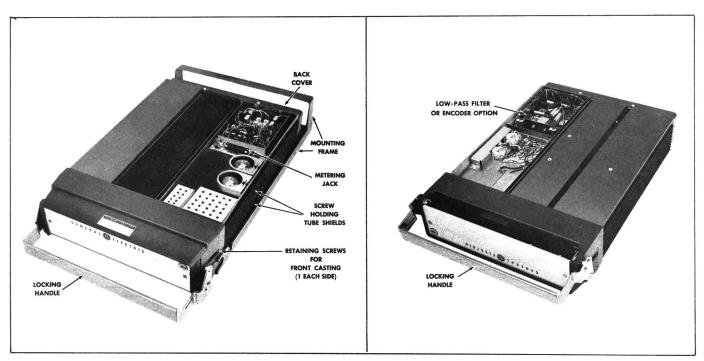


Figure 2 - Top Cover Removed

NOTE -

The tube shields for the 80-watt transmitter are spring-loaded, and can be pulled off of the tube.

To remove transmitter from system frame -

1. Loosen the two retaining screws in the front casting (see Figure 2) and pull casting away from the system frame.

Figure 3 - Bottom Cover Removed

- 2. Remove the four screws in the back cover.
- 3. Remove the two screws holding the transmitter at each end of the system frame.
- 4. Disconnect the antenna jack in front of the transmitter and the 20-pin feed-thru connector at the back of the transmitter, and slide the unit out of the system frame.

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R12) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator Model 4EX6A10
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Models 4EX3A10 or 4EX8K10, 11

PROCEDU

- Connect the audio oscillator and the meter across audio input terminals J5 (Green-Hi) and J6 (Black-Lo) on GE Test Set or across J1 (Mike High) and J2 (Mike Low) on the Exciter Board.
- 2. Apply a 1.0-volt signal at 1000 Hz to Test Set or across J1 and J2 on
- 3. For transmitters without Channel Guard, set the MOD ADJUST (R12) for a 4.5-kilohertz swing (13.5 KHz) for wide band) with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set the Channel Guard MOD ADJUST (R34) for 0.75 KHz tone deviation. Then repeak L1/L2 and L3/L4 as shown in Step 1 of Transmitter Alignment Procedure. Reset tone deviation to 0.75 KHz deviation. Remove the tone to the transmitter by unplugging leads to J7 and J8 on Exciter Board, or by switching to a non-Channel Guard frequency in multifrequency units. Next, apply a 1.0 volt signal at 1000 Hz and set MOD ADJUST (R12) for 3.75 KHz deviation (4.5 KHz minus 0.75-KHz tone deviation)
- For multi-frequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

PA PLATE POWER INPUT

For FCC purposes, the PA Plate power input can be determined by measuring the PA Plate voltage and the plate current indication, and using the following formula:

ET-58-A & B:
$$P_i = \frac{\text{Plate Voltage x Plate Current Indication}}{3.0}$$

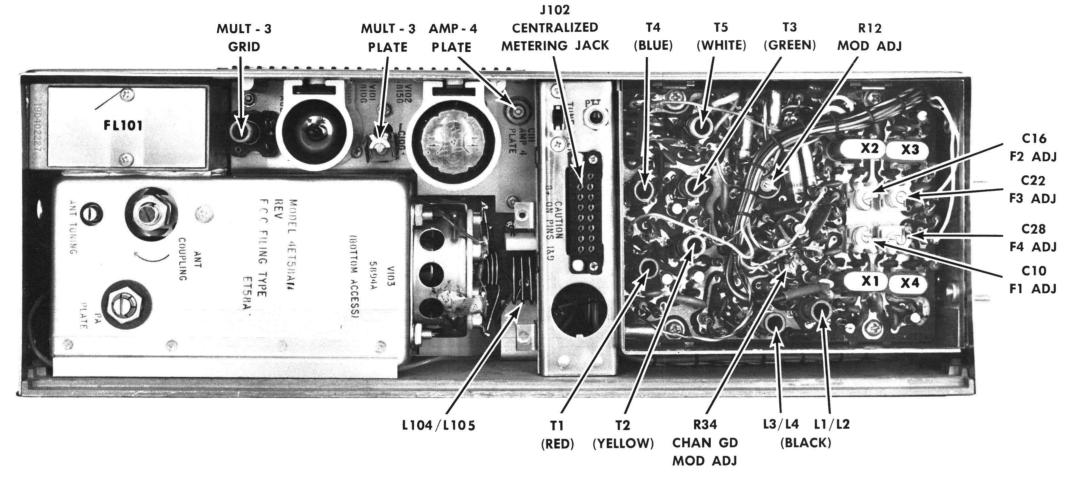
Where:

P; is the power input in watts.

Plate voltage is measured with GE Test Set in position G, using the 1000-volt scale (or measured from J102-1 to -16 with multimeter).

Plate current indication is measured with GE Test Set in Position G, using the TEST 1 scale (or measured from J102-1 to -9 with multimeter).

3.0 is the value of the plate current metering resistor in ohms.



TRANSMITTER ALIGNMENT

EQUIPMENT REQUIRED

 GE Test Set Models 4EX3A10, 4EX8K10 or 11, Station Metering Panel, or a 20,000 ohms-per-volt Multimeter with a 1-volt scale.

PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place crystal (operating frequency : 12) in crystal socket XY1.
- 2. For a large change in frequency or a badly misaligned transmitter, set crystal trimmer C10 to mid-capacity. If multi-frequency transmitter, set all trimmers to mid-capacity and tune transmitter on channel with the highest frequency (except for Step 12).
- 3. Place the TUNE-OPERATE switch (S102) in the TUNE position.
- 4. Connect Test Set Model 4EX3A10 to the Transmitter Centralized Metering Jack J102. If using Multimeter, connect the positive lead to J102-16 (Ground) except for Steps 6 through 16.
- 5. For a large change in frequency or a badly misaligned transmitter, set the slugs in the Exciter coils at the bottom of the coil form, and the slug of MULT-3 GRID (Z101/Z102) at the top of the coil form.

METER

6. All adjustments are made with the transmitter keyed.

STEP	SET	- at J102	CONTROL	READING	PROCEDURE
				EXCITE	R BOARD
1,	A (MULT-1)	Pin 10	L1/L2 (and L3/L4 with Channel Guard)	0.8 v (0.5 v Minimum)	Tuning the modulator is a critical adjustment. Carefully tune $\rm L1/L2$ for maximum meter reading. For channel guard or wideband transmitters, alternately tune $\rm L1/L2$ and $\rm L3/L4$ for maximum meter reading.
2.	A (MULT-1)	Pin 10	T1	See Pro- cedure	Tune Tl for a small peak in meter reading (not required unless changing frequency).
3.	B (MULT-2)	Pin 2	T2, T1 and T3	0.65 v (0.5 v Minimum	Tune T2 and then T1 for maximum meter reading. Then tune T3 for minimum meter reading (not required unless changing frequency).
4.	C (AMPL-3)	Pin 3	T4, T3 and T5	0.6 v (0.5 v Minimum	Tune T4 and then T3 for a maximum meter reading. Then tune T5 for minimum meter reading (not required unless changing frequency).
			MUI	LT-3 AND PO	WER AMPLIFIER
5.	D (MULT-3)	Pin 4	MULT-3 GRID (Z101/Z102) & T5	0.6 v (0.45 v Minimum)	Tune MULT-3 GRID and then T5 for maximum meter reading.
6.	E (AMPL-4)	Pin 5	MULT-3 PLATE (C106)	0.55 v (0.45 v Minimum)	Tune MULT-3 PLATE for maximum meter reading.
7.	F (PA GRID)	Pin 14(+) and Pin 6 (-)	AMPL-4 PLATE (C111) and L104/ L105	1.0 v Maximum (0.65 v Minimum)	Alternately tune AMPL-4 PLATE and adjust interstage coupling (L104/L105) for maximum meter reading (not over 1 volt).
8.					Rotate ANT COUPLING fully counterclockwise.
9.	G (PA PLATE)	High B-pl	WARNING us on Pins 1 and 9,	Minimum	Carefully tune PA PLATE for minimum meter reading.
		Pin 1(+) PA PLATE (C112) Pin 9(-)			
10.					Place S102 (TUNE-OPERATE) switch in OPERATE position.
11.	G (PA PLATE)	Pin 1(+) and Pin 9(-)	ANT COUPLING	Minimum	Adjust ANT COUPLING clockwise for minimum meter reading.

FOR SINGLE-FREQUENCY TRANSMITTERS

12.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	PA PLATE (C112)	Minimum	Tune C112 (PA PLATE) for minimum meter reading.						
13.	11	II.	" ANT TUNING and ANT COUPLING 0.55 v Alternately tune ANT TUNING for maximum meter reading adjust ANT COUPLING clockwise for a meter reading of volts.								
14.	"	"	PA PLATE (C112)	Minimum	Retune PA PLATE for a minimum meter reading.						
15.	11	11	ANT COUPLING	0.7 v	Adjust ANT COUPLING for a meter reading of 0.7 volts.						
16.	F (PA GRID)		AMP-4 PLATE (C111)	Maximum	Retune AMP-4 PLATE for maximum meter reading.						
				FREQUENCY	ADJUSTMENT						
17.					With no modulation, adjust crystal trimmer C10 (or C16, C22, C28 as required) for proper oscillator frequency. Next, refer to the MODULATION ADJUSTMENT.						
					NOTE						
					For proper frequency control of the transmitter, it is recommended that all frequency adjustments be made when the equipment is at a temperature of approx. 75° F. In no case should frequency adjustments be made when the equipment is outside the temperature range of 50° to 90° F.						

FOR MULTI-FREQUENCY TRANSMITTERS

G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	PA PLATE (C112)	Minimum	Switch to the lowest frequency and tune PA PLATE for minimum meter reading.
**	11	ANT TUNING (C114) and ANT COUPLING	0.7 v	Switch back to the highest frequency. Alternately tune ANT TUNING and adjust ANT COUPLING clockwise for a meter reading of 0.7 volts.
E (AMPL-4)	Pin 5	MULT-3 PLATE (C106)	Maximum	Tune MULT-3 PLATE for maximum meter reading.
F (PA GRID)	Pin 14 (+) and Pin 6 (-)	AMP-4 PLATE (C111)	Maximum	Tune AMP-4 PLATE for maximum meter reading
G (PA PLATE)	Pin 1 (+) and Pin 9 (-)		0.7 v Minimum	The PA PLATE reading should be approximately 0.7 volts on both frequencies. AMP-4 PLATE may be retuned slightly until this reading is obtained.
			FREQUENCY	ADJUSTMENT
				With no modulation, adjust crystal trimmers C10 (C16, C22, or C28 as required) for proper oscillator frequency. Next refer to the MODULATION ADJUSTMENT.
				NOTE -
				For proper frequency control of the transmitter, it is recommended that all frequency adjustments be made when the equipment is at a temperature of approx. 75° F. In no case should frequency adjustments be made when the equipment is outside the temperature range of 50° to 90° F.

ALIGNMENT PROCEDURE

LBI-3868

132—174 MHZ, 80-WATT MASTR TRANSMITTER MODELS 4ET58A30-41 & 4ET58B10-15

Issue 3

LBI-3868

TEST PROCEDURES

in servicing a transmitter that is operating--but not the "Service Check" and the additional corrective properly. Problems encountered could be low power output. low B plus, tone and voice deviation, defective audio sensitivity and modulation adjust control set too high. By following the sequence of test steps aligned to the proper operating frequency. starting with Step 1, the defect can be quickly

These Test Procedures are designed to assist you localized. Once a defect is pin-pointed, refer to measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitter Test Procedures, be sure the transmitter is tuned and

TEST EQUIPMENT REQUIRED

for test hookup as shown:

1. Wattmeter similar to: 2. VTVM similar to: 3. Audio Generator similar to: 4. Deviation Meter (with a .75 KHz scale) similar

Bird #43 Jones #711N

Triplett #850 Heath #1M-21

GE Model 4EX6AlO or Heath #1G-72

Measurements #140 Lampkin #205A

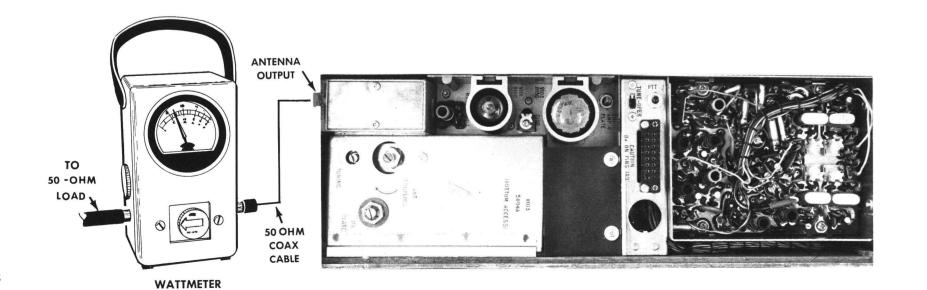
5. Multipmeter similar to:

GE METERING TEST SET MODEL 4EX3A10 or Triplett #631 or 20.000 ohms-per-volt voltmeter

STEP 1

POWER MEASUREMENT TEST PROCEDURE

1. Connect transmitter output to wattmeter as shown below:



2. Key transmitter and check wattmeter for minimum reading of 80 watts.

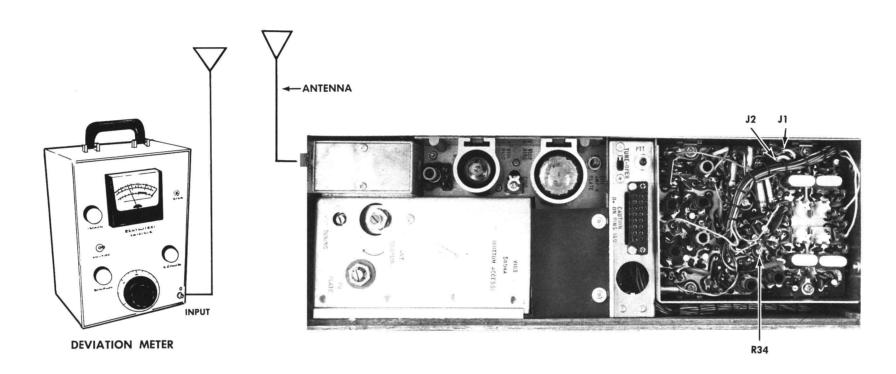
SERVICE CHECK

Refer to Service Hints on Transmitter Troubleshooting Procedure.

STEP 2

TONE DEVIATION WITH CHANNEL GUARD **TEST PROCEDURE**

1. Setup Deviation Meter and monitor output of transmitter as shown below:



- 2. Unplug the MIC HI terminal from Jl on Transmitter Exciter Board.
- 3. Key transmitter and check for 0.75 KHz deviation. If reading is low or high, adjust Channel Guard MOD ADJUST (R34) for a reading of 0.75 KHz.

NOTES:

The Channel Guard MOD ADJUST (R34) may be adjusted for deviations up to 0.80 KHz for tone frequencies from 71.9 Hz to 82.5 Hz and deviations up to 1.0 KHz for all tone frequencies above 82.5 Hz.

DEVIATION METER



NOTES:

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be peaked carefully to insure proper performance. (Refer to Steps 1 and 2 in the Transmitter Alignment Chart).
- 2. The tone Deviation Test Procedures should be repeated everytime the Tone Frequency is changed.

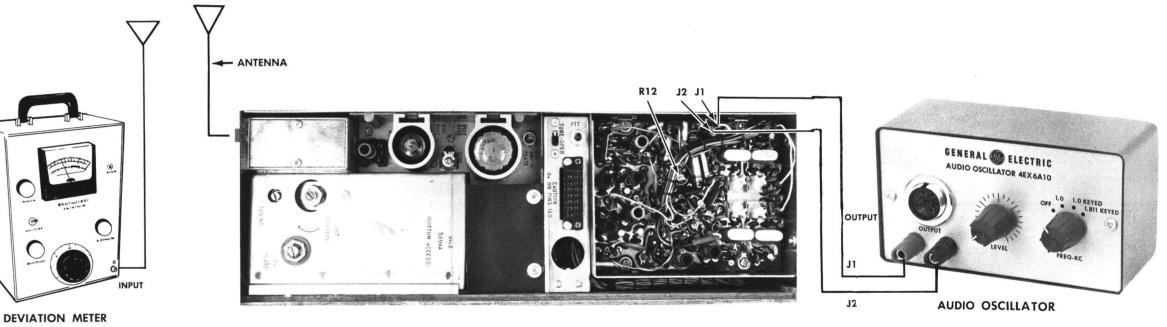
SERVICE CHECK

If the 0.75 KHz deviation is not obtainable when adjusting R34, replace the Tone Transmitter reed.

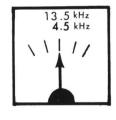
STEP 3

VOICE DEVIATION AND SYMMETRY **TEST PROCEDURE**

- 1. Unplug the High and Low Mike leads from the Exciter Board Jacks Jl and J2.
- 2. Connect test equipment to transmitter as shown below:



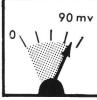
- 3. Set the generator output to 1.0 VOLTS RMS and frequency to 1 KHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency
- 5. Deviation reading should be ± 4.5 KHz. (± 13.5 KHz wide band).
- 6. Adjust "Modulation Adjust Control" R12 until deviation reads DEVIATION METER 4.5 KHz (13.5 KHz wide band) on plus (+) or minus (-) deviation. whichever is greater. This adjustment should be made with the correct level of tone applied on Channel Guard transmitters.



NOTES: --MASTR transmitters are adjusted for 4.5 KHz (13.5 KHz wide band) deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 KHz (15 KHz wide band) under the worst conditions of frequency, voltage and temperature.

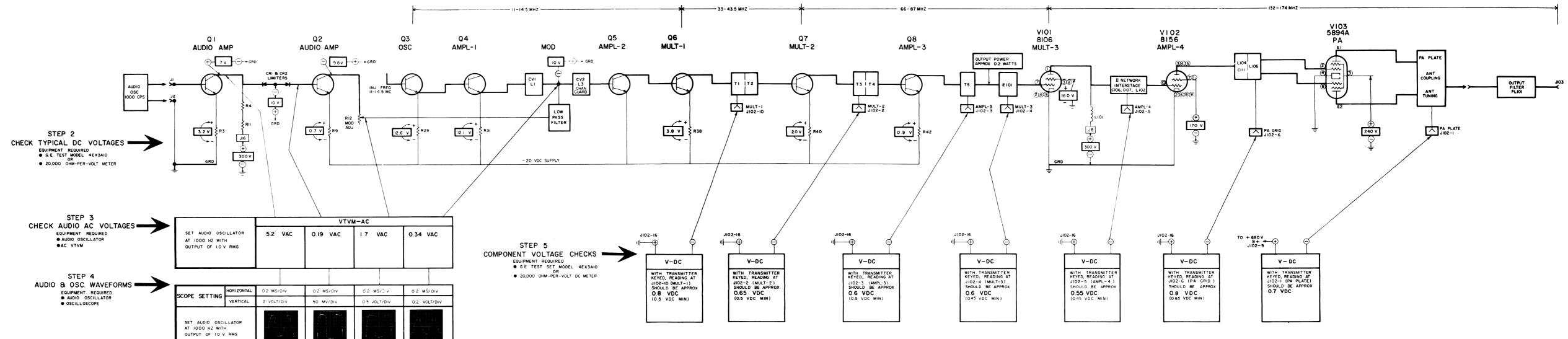
If the deviation reading plus (+) and minus (-) differs by more than 0.5 KHz, (1.5 KHz wide band) check the following:

- 1. Recheck Step 1 as shown in the Transmitter Alignment Chart.
- 2. Check Audio Sensitivity by reducing generator output until deviation falls to 3.3 KHz (10 KHz wide band). Voltage should be LESS than 90 millivolts.



STEP I - QUICK CHECKS

POWER		CHECK VOL			D METERING	JACK J102	 				
OUTPUT					numbers positions			PROBABLE DEFECT			
	Pins 10 & 16 A	Pins 2 & 16 B	Pins 3 & 16 C	Pins 4 & 16 D	Pins 5 & 16 E	Pins 6 & 14 F	Pins 1 & 9 G	TROBRIDED DIFFICE			
Low	0.8 v	0.65 v	0.6 v	0.6 v	0.55 v	Low	0.7 v	Weak 5894A or Loose Hard- ware in output tank circuit, or bad filter.			
0	0.8 v	0.65 v	0.6 v	0.6 v	0.55 v	.37 v	0	Open 58,94A			
Low	0.8 v	0.65 v	0.6 v	0.6 v	0.55 v	Low	0.7 v	Weak 8156			
0	0. 8 v	0.65 v	0.6 v	0.6 v	.37 v	.37 v	0	Open Filament on 8156			
0	0.8 v	0.65 v	Low	.18 v	.37 v	.37 v	0	Open Filament on 8106			
0	0.8 v	0.65 v	0 or over 1.0 v	.18 v	.37 v	.37 v	0	Defective Q8			
0	0.8 v	0 or over 1.0 v	0	. 18 v	.77 v	.37 v	0	Defective Q7			
0	over 1.2 v	o	0	.18 v	.37 v	.37 v	0	Shorted Q6 or Open Q5			
0	0	0	0	.18 v	.37 v	.37 v	0	Defective Q3-Q6 or Modulator (see Note A)			
NOTE A -	Locali	ze trouble l	y checking	:							
1.	-20 vo	olt DC supply	y at J102-1	2-16.							
2.	Measur	e 12.1 VDC a	cross Q4 e	mitter r	esistor R31	(1500 oh	ms), then:				
(a)	Remove proper	crystal- a	slight var	iation i	n R31 volta	ge readin	g indicate	s Q3 and Q4 stages operating			
(b)	If no	voltage is n	measured, c	heck key	ing leads (R3-CR6, Q	3, Q4.				
(c)	With c Q5 and	rystal remov	ed, short	Q5 base erly. D	to emitter. efect may b	A voltag	ge reading lator.	above 1.0 volt indicates			
(d)	If mod	ulator is de	efective, c	heck vol	tage variab	le diodes	CV1 and C	V2.			

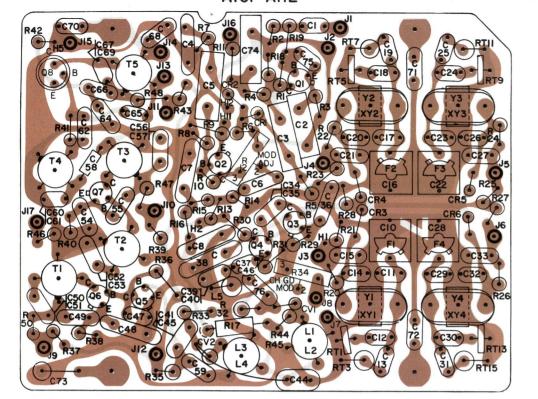


RC-1188B

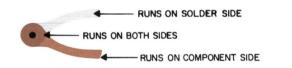
TROUBLESHOOTING PROCEDURE

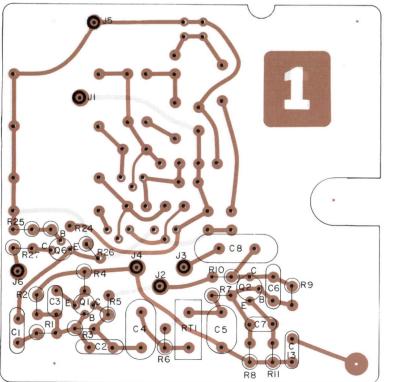
132-174 MHZ, 80-WATT MASTR TRANSMITTER MODELS 4ET58A30-41 & 4ET58B10-15

EXCITER AIOI-AII2



(19C303483, Sh. 1, Rev. 7) (19C303483, Sh. 2, Rev. 7)





OUTLINE DIAGRAM

132-174 MHZ, 80-WATT MASTR TRANSMITTER MODELS 4ET58A30-41 & 4ET58B10-15

C4 PTI C5 C	7 C 3 RII	LEAD	IDENTIFICATION
LOW-PASS FILTER	(19C211800 Sh 1 Rev 1)		

TRANSISTOR	EMI	TTER	BA	SE	COLL	LECTOR	
	-	+		+	-	+	
QI	6.5K	6.8K	240K	12K	50K	20K	
Q2	6.2K	4K	70K	IOK	9 8K	IOK	
Q3	9K	2.7K	9K	2.7K	100	100	
Órt .	7K	5K	9K	2 7K	100	100	
Q5	5K	2.7K	70K	6.8K	3.7K	2.3K	
Q6	4K	3.2K	3.7K	2.3K	175	175	
Q7	5.2K	2.9k	5K	2.7k	465	465	
08	5K	2.7K	5K	2.7K	67	67	

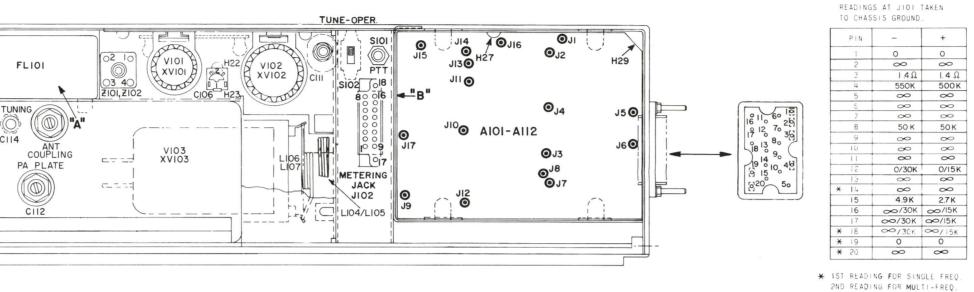
TRANSISTOR	EMI	TTER	BAS	E	COLL	ECTOR
	-	+	-	+	-	+
QI	LIK	14K	240K	30K	60K	35K
Q2	LK	1K	70K	4.3K	14K	18K
Q3	2.6K	2.FK	IOK	5.5K	2 7K	5. IK
Ort.	1.5K	1.5K	2.6K	2 5K	2.7K	5. IK
Q5	0	0	70K	3.2K	8.2K	3.8K
Q6	340	360	8k	3.8K	3K	5 IK
Q7	60	180	0	0	2.3K	5.5H
08	27	27	47	47	2.6K	5K

RESISTANCE READINGS

ALL READINGS ARE TYPICAL READINGS MEASURED WITH A 20.000 OHM-PER-VOLT METER AND JIOI DISCONNECTED. + OR - SIGNS SHOW METER LEAD GROUNDED.

FOR READINGS OF: USE SCALE: 1-100Ω 100-1KΩ 1K-50KΩ 50-∞Ω X 10 X 1.000 X 100.000

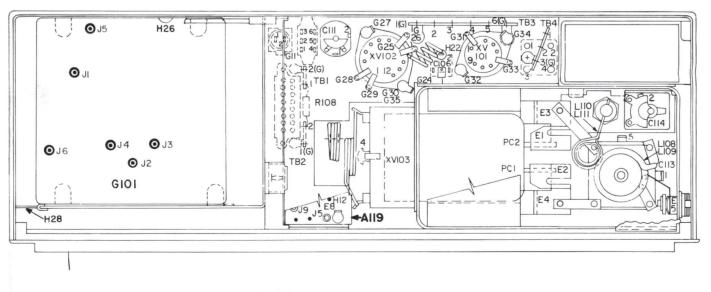
TOP VIEW



●H9 R4



BOTTOM VIEW

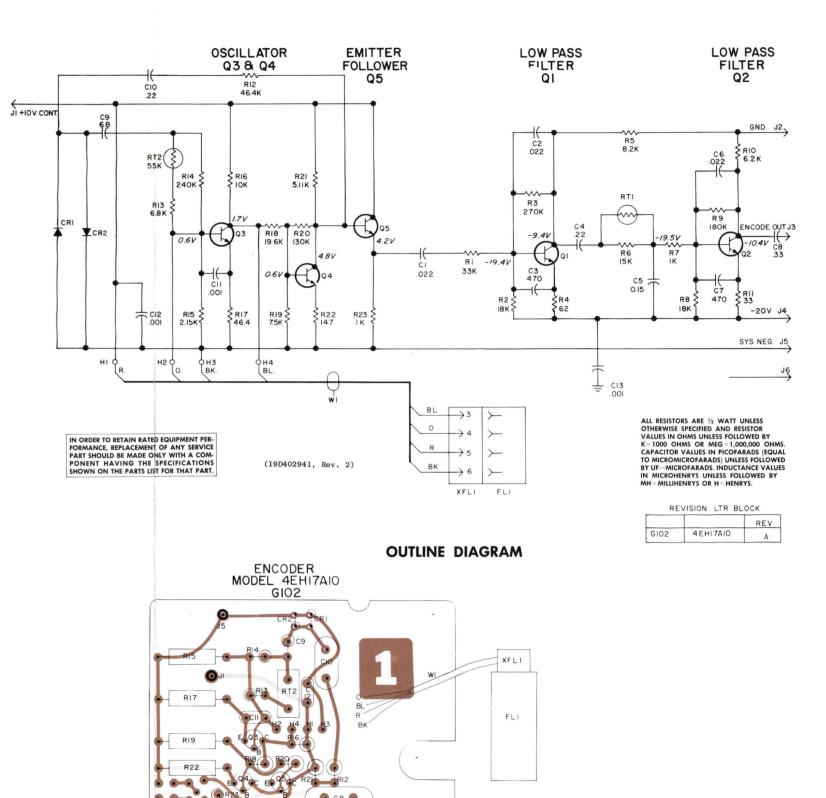


EADINGS	TAKEN	FROM	TUBE	SOCKET	PINS	TO	CHASSIS	GROUND	

PIN	1	2	3	14	5	6	7	8	9	10	[]:	12
XVIOI	550K	0	583 K	0	1.4 Ω	0	30 K	583 K	0			
XV105	0	0	550 K	550K	550 K	0	83K	0	0	60K	83K	1.4 Ω
XV103	1.4Ω	50K	550 K	0	0.90	50K	0					

CHANNEL GUARD ENCODER MODEL 4EH17A10

SCHEMATIC DIAGRAM

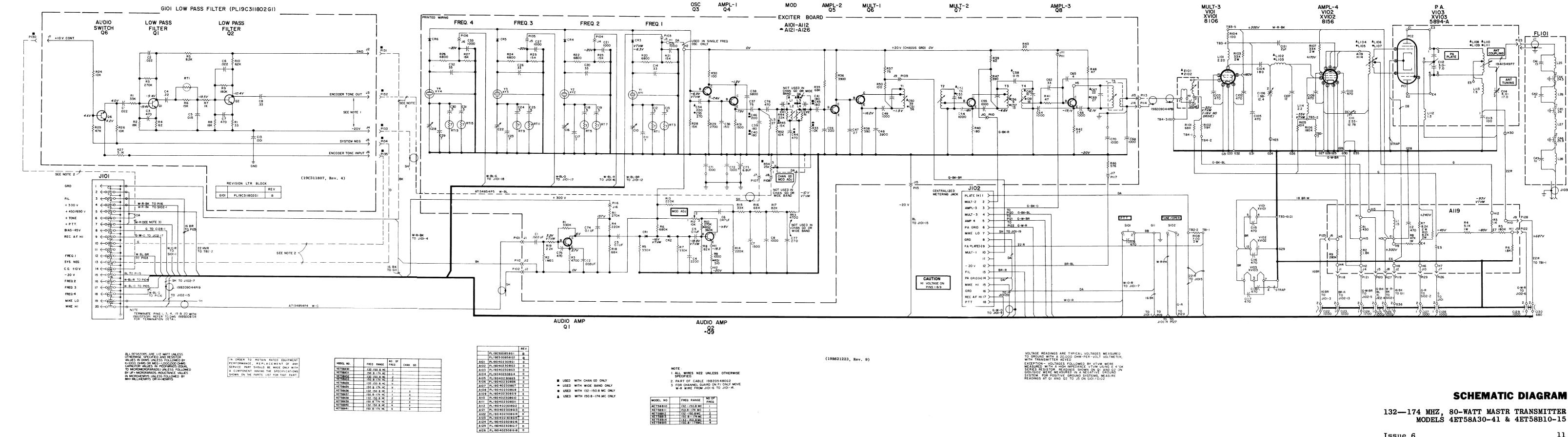


(19C311861, Rev. 3) (19C311800, Sh. 1, Rev. 1) (19C311800, Sh. 2, Rev. 1)

PIN	1	2	3	4	5	6	7	8	9	10	- 11	12
XVIOI	550K	0	583 K	0	1.4 Ω	0	30 K	583 K	0			
XV102	0	0	550 K	550K	550 K	0	83K	0	0	60K	83K	1.4 Ω
XV103	1.4Ω	50K	550 K	0	0.9Ω	50K	0					

(19R621240, Rev. 6)

Issue 5



132-174 MHZ, 80-WATT MASTR TRANSMITTER MODELS 4ET58A30-41 & 4ET58B10-15

PARTS LIST

LBI-3878C

132-174 MHz TRANSMITTER MODELS 4ET58A30 - 4ET58A41 MODELS 4ET58B10 - 4ET58B15 SYMBOL G-E PART NO

5496219-P7

C300685-P93

196219-**P**751

194481-P111

5496372-P50

496219-P467

5496372-P327

194481-P131

5496372-P145

5496372-P345

5493366-P470J

496372-P45

196372-P347

5496219-P749

494481-P129

194481-P111

5496219-P253

5496219-**P2**57

5496219-P253

5496219-**P**257

496219-P440

5496219-P343

5491601-P35

5493366-P220K

5496219-P241

5496219-P244

5496219**-P**51

5494481-P111

5496219-P35

5494481-P111

496219-P247

494481-P111

C29

C32

C36

C37

C38

C39

C40

C44

C47

C48

C50

C53

C57

C59

C60

C62

	DESCRIPTION
	EXCITER BOARD ASSEMBLY A101
1	Polyester: .022 µf ±20%, 50 VDCW.
i l	Polyester: .033 µf ±20%, 50 VDCW.
1	Polyester: 0.1 μf ±20%, 50 VDCW.
·	Ceramic disc: .0022 µf ±10%, 500 VDCW.
1	Polyester: 0.1 \(\mu f \pm 20\%, 50 \cdot VDCW. \) Polyester: .047 \(\mu f \pm 20\%, 50 \cdot VDCW. \)
	Ceramic disc: .0015 µf ±10%, 500 VDCW.
5493367-P1000K	Silver mica: .001 µf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.
5491271-P106	Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189.
5496219-P7	Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
19C300685-P93	Ceramic disc: 5 pf \pm 0.1 pf, 500 VDCW, temp coef 0 PPM.
5496219-P751	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.
5494481-P111	Ceramic disc: .001 μf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
5491271-P106	Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189.
5496219-P7	Ceramic disc: 7 pf ± 0.5 pf, 500 VDCW, temp coef 0 PPM.
19C300685-P93	Ceramic disc: 5 pf ± 0.1 pf, 500 VDCW, temp coef 0 PPM.
5496219-P751	Ceramic disc: 33 pf $\pm 5\%$, 500 VDCW, temp coef -750 PPM.
5494481-P111	Ceramic disc: .001 μf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
5491271-P106	Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.
	Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.
19C300685-P93	Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.
5496219-P751	Ceramic disc: 33 pf $\pm 5\%$, 500 VDCW, temp coef -750 PPM.
5494481-P111	Ceramic disc: .001 μf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
5491271-P106	Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189.
	5491271-P106 5496219-P7 19C300685-P93 5496219-P751 5494481-P111 5491271-P106 5496219-P7 19C300685-P93 5496219-P751 5494481-P111 5491271-P106 5496219-P7 19C300685-P93

_		
	DESCRIPTION	SYMBOL
	Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.	C69
	Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	C70 thru C72
	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.	C73
	Ceramic disc: .001 µf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C74
	Ceramic disc: 220 pf ±5%, 500 VDCW, temp coef -2200 PPM.	C75
	Ceramic disc: 270 pf ±5%, 500 VDCW, temp coef -2200 PPM.	C76
	Ceramic disc: 150 pf ±5%, 500 VDCW, temp coef -220 PPM.	C77
	Ceramic disc: 75 pf ±10%, 500 VDCW, temp coef -4700 PPM,	
	Ceramic disc: 6800 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	CR1 and CR2
	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -3300 PPM.	CR3 thru
	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -4700 PPM.	CR6
	Mica: 180 pf ±10%, 100 VDCW; sim to Electro Motive Type DM15.	and CV2
	Silver mica: 470 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15.	J1
	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -2200 PPM.	J17
	Ceramic disc: 200 pf ±10%, 500 VDCW, temp coef -4700 PPM.	L1
	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -750 PPM.	L2
	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	L3 R1
	Ceramic disc: .001 µf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	1.4
	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.	L5
	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.	
	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.	Q1 and
	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.	Q2 Q3
	Ceramic disc: .001 μf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.	thru Q5 Q6
	Ceramic disc: 9 pf ±0.25 pf, 500 VDCW, temp coef -220 PPM.	and Q7
	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -150 PPM.	Q8 Q9
	Tubular: 0.15 pf ±10%, 500 VDCW; sim to Quality Components Type MC.	
	Silver mica: 220 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.	Rl
	Ceramic disc: 10 pf ±5%, 500 VDCW, temp coef -80 PPM.	R2 R3
	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -80 PPM.	R4
	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.	R5 R6
	Ceramic disc: .001 µf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R7
	Ceramic disc: 4 pf ± 0.25 pf, 500 VDCW, temp coef 0 PPM.	R8 R9
	Ceramic disc: .001 μ f $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.	R10 and
	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -80 PPM.	R11
	Ceramic disc: .001 µf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	
		L

SYMBOL	GE PART NO.	DESCRIPTION
C69	5496219- P 249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -80 PPM,
C70 thru C72	5494481-P111	Ceramic disc: .001 µf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C73	5496267-P18	Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague Type 150D.
C74	19A115414-P13	Tubular, polyester: 0.1 µf ±20%, 200 VDCW.
C75	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RM Type JF Discap.
C76	5493366-P470K	Mica: 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.
C77	5493366-P270K	Mica: 270 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.
		DIODES AND RECTIFIERS
CR1 and	19A115250-P1	Silicon.
CR2	104115000 79	0.11
CR3 thru CR6	19A115603-P1	Silicon.
CV1 and	5495769-P8	Silicon, capacitive.
CV2		JACKS AND RECEPTACLES
J1	4033513-P4	Contact, electrical; sim to Bead Chain L93-3.
thru J17		
		INDUCTORS
Ll	19B204526-G2	Coil. Includes tuning slug 5491798-P2.
L2	19B204526-G1	Coil. Includes tuning slug 5491798-P2.
L3	19B204526-G4	Coil. Includes tuning slug 5491798-P2.
Rl	3R152-P333J	Composition: 33,000 ohms ±5%, 1/4 w.
L4	19B204526-G3	Coil. Includes tuning slug 5491798-P2.
R1	3R152-P333J	Composition: 33,000 ohms ±5%, 1/4 w.
L5	7488079- P4 8	Choke, RF: 27 µh ±10%, 1.4 ohms DC res; sim to Jeffers 4422-9K.
		TRANSISTORS
Q1 and	19A115123-P1	Silicon, NPN; sim to Type 2N2712.
Q2 Q3	19A115330-P1	Silicon, NPN.
thru Q5		
Q6 and Q7	19A115328-P1	Silicon, NPN.
Q8	19A115329-P1	Silicon, NPN.
Q9	19A115362-P1	Silicon, NPN; sim to Type 2N2925.
	1	RESISTORS
R1	3R77-P334K	Composition: 0.33 megohm ±10%, 1/2 w.
R2	3R77-P105K	Composition: 1 megohm ±10%, 1/2 w.
R3	3R77-P472K	Composition: 4700 ohms ±10%, 1/2 w.
R4	3R77-P224K	Composition: 0.22 megohm ±10%, 1/2 w.
R5	3R77-P334K	Composition: 0.33 megohm ±10%, 1/2 w.
R6	3R77-P684K	Composition: 0.68 megohm ±10%, 1/2 w.
R7	3R77-P334K	Composition: 0.33 megohm ±10%, 1/2 w.
R8	3R77-P823K	Composition: 82,000 ohms ±10%, 1/2 w.
R9	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
R10	3R77-P274K	Composition: 0.27 megohm ±10%, 1/2 w.
and R11		
	1	

GE PART NO.

19B209358-P106

19B201969-P6

3R77-P224K

3R77-P683K

3R77-P222K

3R77-P153K

3R77-P682K

3R77-P272K

3R77-P152K

L9B209358-P10

3R77-P683K

3R77-P391K

3R77-P181K

3R77-P270K

3R77-P153K

3R77-P391K

3R77-P511J

3R152-P472K

19B209284-P6

19B209284-P2

R12*

and R14

R15

R16

R17

R18

R19

R21

R22

R23

R24

R26

R29

R30

R31

R34*

R35

R36

R37

R38

R39

R40

R42

R43

R44

R45

R47

R48

R50

R51

R53

RT1

RT5

RT7

DESCRIPTION	SYMBOL	GE PART NO.	
Variable, carbon film: approx 75 to 10,000 ohms	RT9	19B209284-P6	Disc blue
±10%, 0.25 w; sim to CTS Type X-201. In Models 4ET58A30-35 of REV C and earlier: In Models 4ET58A36-41 of REV D and earlier:	RT11	19B209284-P2	Rod:
In Models 4ET58B10-15 of REV C and earlier: Variable, carbon film: .01 megohm ±20%, 0.1 w, sim to Centralab Series 4.	RT13	19B209284-P6	Disc blue
Composition: 0.22 megohm ±10%, 1/2 w.	RT15	19B209284-P2	Rod:
G			
Composition: 33,000 ohms ±10%, 1/2 w.	Tl	19B204534-G1	Coil
Composition: 68,000 ohms ±10%, 1/2 w.	Т2	19B204531-G1	Coil
Composition: 82,000 ohms ±10%, 1/2 w.	Т3	19B204535-Gl	Coil
Composition: 68,000 ohms ±10%, 1/2 w. Composition: 2200 ohms ±10%, 1/2 w.	Т4	19B204535-G2	Coil
Composition: 6800 ohms ±10%, 1/2 w.	Т5	19B204537-G1	Coil
Composition: 15,000 ohms ±10%, 1/2 w.			
Composition: 6800 ohms ±10%, 1/2 w.	XY1		Refe
Composition: 15,000 ohms ±10%, 1/2 w.	thru XY4		were.
Composition: 6800 ohms $\pm 10\%$, $1/2$ w.			
Composition: 15,000 ohms ±10%, 1/2 w.			When
Composition: 6800 ohms ±10%, 1/2 w.			exac
Composition: 15,000 ohms ±10%, 1/2 w.			Crys
	Y1 thru Y4	19B206175-P6	Quar rang
Composition: 2700 ohms ±10%, 1/2 w.	¥1	19B206175-P7	Quar
Composition: 100 ohms ±10%, 1/2 w.	thru Y4		range
Composition: 1500 ohms ±10%, 1/2 w.			
Composition: 10,000 ohms ±10%, 1/2 w.	A119		
Variable, carbon film: approx 75 to 25,000 ohms $\pm 10\%$, 0.25 w; sim to CTS Type X-201. In Models 4ET58A36-41 of REV D and earlier: Variable, carbon film: 25,000 ohms $\pm 20\%$, 0.1 w.	C2	5494481-P7	Cerai
Composition: 68,000 ohms $\pm 10\%$, $1/2$ w.	!		
Composition: 3900 ohms $\pm 10\%$, $1/2$ w.	J1	4033513-P4	Come
Composition: 75 ohms ±5%, 1/2 w.	thru J10	4033313-P4	Cont
Composition: 390 ohms $\pm 10\%$, $1/2$ w.	""		
Composition: 62 ohms $\pm 5\%$, $1/2$ w.	Lı	7488079-P34	Chok
Composition: 180 ohms ±10%, 1/2 w.			to J
Composition: 47 ohms $\pm 10\%$, $1/2$ w.			
Composition: 27 ohms ±10%, 1/2 w.	R1	3R77-P431J	Comp
Composition: 20 ohms ±5%, 1/2 w.	R2	3R77-P182K	Comp
Composition: 22,000 ohms ±10%, 1/2 w.	R3	3R77-P102K	Comp
Composition: 15,000 ohms ±10%, 1/2 w. Metal film: 576,000 ohms ±2%, 1/2 w.	R4	3R78-P512J	Comp
Metal film: 576,000 ohms ±2%, 1/2 w. Composition: 390 ohms ±10%, 1/2 w.	R5	3R77-P184K	Comp
Composition: 47 ohms ±10%, 1/2 w.	R6	3R77-P182K	Comp
Composition: 100 ohms ±10%, 1/2 w.	R7	3R79-P822K	Comp
Composition: 510 ohms ±5%, 1/2 w.	R8	3R78-P473K	Comp
Composition: 0.36 megohm ±5%, 1/2 w.	R9	19A116278-P444	Meta
Composition: 4700 ohms $\pm 10\%$, $1/4$ w.	R10	3R79-P822K	Comp
Disc: 75 ohms res nominal at 25°C , color code blue.	G101		
Rod: 21,400 ohms res nominal at 25°C, color code red.			
Disc: 75 ohms res nominal at 25°C, color code blue.	C1*	19B209243-P103	Poly
Rod: 21,400 ohms res nominal at 25°C, color code red.		19B209243-P2	In M Poly
	1.1		I

	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.
	19B209284-P6	Disc: 75 ohms res nominal at 25°C, color code blue.	C2	19B209243-P3
	19B209284-P2	Rod: 21,400 ohms res nominal at 25°C, color code red.	СЗ	5494481-P107
	19B209284-P6	Disc: 75 ohms res nominal at 25°C, color code	C4	19B209243-P9
	19B209284-P2	blue.	C5	19B209243-P8
	198209204-F2	Rod: 21,400 ohms res nominal at 25°C, color code red.	C6	19B209243-P3
			C7	5494481-P107
	19B204534-G1	Coil. Includes tuning slug 5491798-P4.	C8	19B209243-P14
	19B204531-G1	Coil. Includes tuning slug 5491798-P4.	C13	5494481-P111
	19B204535-G1	Coil. Includes tuning slug 5491798-P4.		
	19B204535-G2	Coil. Includes tuning slug 5491798-P4.		
	19B204537-G1	Coil. Includes tuning slug 5491798-P4.	J1 thru	4033513-P4
		SOCKETS	J6	
		Refer to Mechanical Parts (RC-1628).		19A115123-P1
			Q1 and Q2	19A115123-P1
			Q6	19A115123-P1
		When reordering give GE Part No. and specify exact freq needed.		13/11/0120-F1
	19B206175-P6	Crystal Freq = (OF ‡ 12).	R1	3R77-P333K
	198206175-P6	Quartz: freq range 11,000 to 12,566 KHz, temp range -30°C to +85°C. (132-150.8 MHz Transmitter)	R2	3R77-P183K
	19B206175-P7	Quartz: freq range 12,566 to 14,500 KHz, temp	R3	3R77-P274K
	135200110 11	range -30°C to +85°C. (150.8-174 MHz Transmitter)	R4	3R77-P620J
			R5	3R77-P822K
		COMPONENT BOARD ASSEMBLY 19C303615-G1	R6	3R77-P153K
			R7	3R77-P102K
			R8	3R77-P183K
	5494481-P7	Ceramic disc: 470 pf ±20%, 500 VDCW; sim to RMC Type JF Discap.	R9	3R77-P184K
		110FG 1112 210F 210F 210F	R10	3R77-P622J
	4033513-P4	JACKS AND RECEPTACLES	Rll	3R77-P330K
	1033313-24	Contact, electrical; sim to Bead Chain L93-3.	R24	3R77-P103K
			R25	3R77-P473K
	7488079-P34	Choke, RF: 1.5 µh ±10%, 0.28 ohm DC res; sim	R26	3R77-P103K
		to Jeffers 4412-7K.	R27*	3R77-P512K
	3R77-P431J	Composition: 430 ohms ±5%, 1/2 w.	RT1	5490828-P30
	3R77-P182K	Composition: 1800 ohms ±10%, 1/2 w.		
	3R77-P102K 3R78-P512J	Composition: 1000 ohms ±10%, 1/2 w.		
	3R78-P512J 3R77-P184K	Composition: 0.18 magain +10% 1/2 m		
	3R77-P182K	Composition: 0.18 megohm ±10%, 1/2 w. Composition: 1800 ohms ±10%, 1/2 w.	ļ	
	3R79-P822K	Composition: 8200 ohms ±10%, 1/2 w.		19B201074-P304
	3R78-P473K	Composition: 47,000 ohms ±10%, 1 w.		19B205480-G2
	19A116278-P444	Metal film: 0.28 megohms ±2%, 1/2 w.	P130 thru	4029840-P2
	3R79-P822K	Composition: 8200 ohms ±10%, 2 w.	P135	
		OSCILLATORS	1	
		LOW PASS FILTER ASSEMBLY		
		1 9C311802-G1 REV B	C102	5494481-P7
		CADAGITODS	and C103	0.51.01
	19B209243-P103		C104	5496203-P446
	100200210-F103	Polyester: 0.022 µf ±10%, 50 VDCW. In Models earlier than Rev A:		
	19B209243-P2	Polyester: 0.015 µf ±20%, 50 VDCW.	C105	5494481-P7
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CI	\Box	STIMBUL	GE PART NO.	DESCRIP HON	STIMIDUL	GE PART NO.	DESORII TION
C3 \$44441-77		C2	19B209243-P3	Polyester: 0.022 µf ±20%, 50 VDCW.	C106	5491271-P6	Variable, subminiature: approx 2.1-12.7 pf,
Second Column		сз	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to	C107	5490008-P107	Silver mica: 12 pf ±10%, 500 VDCW; sim to
CS 1480481-910				Polyester: 0.22 µf ±20%, 50 VDCW.		5494481-P7	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to
Crast class				·			RMC Type JF Discap.
C12 108200931-94 C13 108200931-94 C13 109200931-94 C13 109200931-94 C13 109200931-94 C13 10920931-94 C13 10920931-94 C13 10920931-94 C13 C		1		·	C111	7481115-P3	
Clid	1			RMC Type JF Discap.	C112	19B200391-P2	Variable: approx 3-7 pf, 2100 v peak.
NECTOPS Final Content Part Pa	- [1		· '	C113		Refer to Mechanical Parts (RC-1628).
ACC 3970 ACC 300 EXCEPTION STATE AND EXCEPTIONS STATE AND EXCEPTIONS STATE AND EXCEPTION STATE AND	İ	C13	5494481-P111	Ceramic disc: .001 µf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	C114	7491398-P4	Variable: 4-17 pf; sim to Teleradio T-9974.
CIN Table				JACKS AND RECEPTACLES	thru	5494481-P7	Ceramic disc: 470 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.
1981 1982		thru	4033513-P4	Contact, electrical; sim to Bead Chain L93-3.	C121	7130348-P6	Tubular: 2 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.
Class				TRANSISTORS		5493392-P7	Ceramic, feed-thru: .001 µf +100%-0%, 500
Case 194151323-P Silicon, RPR; sim to Type 232712,	-		19Al15123-P1	Silicon, NPN; sim to Type 2N2712.			vices, sim to kiten madiey type rase.
## 1 3877-P338K Composition: 33,000 ohms: 105, 1/2 w. ## 3877-P338K Composition: 16,000 ohms: 105, 1/2 w. ## 3877-P338K Composition: 0.27 meyhal 1105, 1/2 w. ## 3877-P308C Composition: 0.27 meyhal 1105, 1/2 w. ## 3877-P308K Composition: 100 ohms: 105, 1/2 w. ## 3877-P308K Composition: 15,000 ohms: 105, 1/2 w. ## 3877-P308K Composition: 10,000 ohms: 105, 1/2 w. ## 3877-P308K Composition: 10,000 ohms: 105, 1/2 w. ## 3877-P308K Composition: 30 ohms: 105	- 🖡	Q2			C130	19B209282-P1	Ceramic, feed thru: 680 pf ±20%, 1000 VDCW; sim to Sprague Type 544C.
R1 3877-P331K Composition: 33,000 chas 105, 1/2 v.		Q6	19Al15123-Pl	Silicon, NPN; sim to Type 2N2712.			
1				RESISTORS	FT 101*		
### 2 3877-74804 Composition: 18,000 ohms 105, 1/2 *. ### 3877-79204 Composition: 520 cohms 105, 1/2 *. ### 3877-79205 Composition: 5200 ohms 105, 1/2 *. ### 3877-79105 Composition: 15,000 ohms 105, 1/2 *. ### 3877-79105 Composition: 15,000 ohms 105, 1/2 *. ### 3877-79105 Composition: 15,000 ohms 105, 1/2 *. ### 3877-79105 Composition: 10,100 ohms 105, 1/2 *. ### 10 3877-79202 Composition: 10,100 ohms 105, 1/2 *. ### 13 3877-79105 Composition: 30 ohms 105, 1/2 *. ### 13 3877-79105 Composition: 30 ohms 105, 1/2 *. ### 13 3877-79105 Composition: 30 ohms 105, 1/2 *. ### 23 3877-79105 Composition: 30 ohms 105, 1/2 *. ### 23 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 24 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 25 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 26 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 26 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 27 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 26 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 27 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 27 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 27 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 27 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 27 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 28 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 28 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 28 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 28 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 28 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 29 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 29 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 29 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 29 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 29 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 29 3877-79105 Composition: 10,000 ohms 105, 1/2 *. ### 29 3877-79105 Composition: 10,000 ohms 105, 1/2 *		Rl	3R77-P333K	Composition: 33,000 ohms ±10%, 1/2 w.	TEIOT.		
### ### ### ### #### #### #### #### ####	*r)	R2	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.		a major, sa sy	The low pass filter is factory tuned. If it is found to be defective it is recommended
A		R3	3R77-P274K	Composition: 0.27 megohm ±10%, 1/2 w.			that the entire filter assembly be replaced
R8	r)	R4	3R77-P620J	Composition: 62 ohms ±5%, 1/2 w.			attenuation.
R7		1		Composition: 8200 ohms ±10%, 1/2 w.			
R8 3877-P183K Composition: 18,000 cham ±105, 1/2 w. R89 3877-P84K Composition: 20.18 magohm ±105, 1/2 w. R10 3877-P303K Composition: 3000 cham ±105, 1/2 w. R24 3877-P303K Composition: 10,000 cham ±105, 1/2 w. R25 3877-P303K Composition: 10,000 cham ±105, 1/2 w. R26 3877-P303K Composition: 10,000 cham ±105, 1/2 w. R27* 3877-P312K Composition: 10,000 cham ±105, 1/2 w. R27* 3877-P312K Composition: 30 cham ±105, 1/2 w. R27* 3877-P312K Composition: 10,000 cham ±105, 1/2 w. R27* 3877-P312K Composition: 5100 cham ±105, 1/2 w. R39* 1000 cham ±105, 1/2 w. L102 198204841-P1 Coil. L103* 198204344-P2 Coil. R27* 198204384-P2 Coil. R27* 198204384-P2 Coil. R28* 198204384-P2 Coil. R28* 198204384-P2 Coil. R28* 198204384-P2 Coil. R28* 198204384-P3 Coil. R28* 198204				· '			LOW PASS FILTER ASSEMBLY 19D402233-G5
R S 3877-P184K Composition: 18,000 ohas 105, 1/2 w. R10 3877-P84K Composition: 0.18 megoma 105, 1/2 w. R11 3877-P30X Composition: 0.18 megoma 105, 1/2 w. R24 3877-P10X Composition: 10,000 ohas 105, 1/2 w. R25 3877-P473K Composition: 10,000 ohas 105, 1/2 w. R26 3877-P10X Composition: 10,000 ohas 105, 1/2 w. R27* 3877-P10X Composition: 10,000 ohas 105, 1/2 w. R27* 3877-P31Z Composition: 10,000 ohas 105, 1/2 w. R27* 3877-P31Z Composition: 10,000 ohas 105, 1/2 w. Added by Rev B. R27* 3877-P31Z Composition: 10,000 ohas 105, 1/2 w. Added by Rev B. R27* 3877-P31Z Composition: 3100 ohas 105, 1/2 w. Added by Rev B. R28* 3877-P31Z Composition: 10,000 ohas 105, 1/2 w. Added by Rev B. R29* 3877-P31Z Composition: 10,000 ohas 105, 1/2 w. Added by Rev B. R29* 3877-P31Z Composition: 10,000 ohas 105, 1/2 w. Added by Rev B. R29* 3877-P31Z Composition: 10,000 ohas 105, 1/2 w. Added by Rev B. Added by	-	1				:	
R10 3R77-P6221 Composition: 6200 ohms:155, 1/2 w. R11 3R77-P305K Composition: 10,000 ohms:105, 1/2 w. R24 3R77-P473K Composition: 10,000 ohms:105, 1/2 w. R25 3R77-P473K Composition: 10,000 ohms:105, 1/2 w. R26 3R77-P103K Composition: 10,000 ohms:105, 1/2 w. R27* 3R77-P512K Composition: 10,000 ohms:105, 1/2 w. R27* 3R77-P512K Composition: 5100 ohms:105, 1/2 w. R27* Added by Rev B. R27* Added by Rev B. R27* Composition: 5100 ohms:105, 1/2 w. R27* Added by Rev B. R27* Added by Rev B. R27* Added by Rev B. R27* Composition: 5100 ohms:105, 1/2 w. R28* B. R29* Composition: 5100 ohms:105, 1/2 w. L101 7488079-P8 Cohe, RF: 2.2 mh 105, 1 ohm DC res; sim to Jeffers 4411-12K. Coil. R27* Coil. R28* Coil. R27* Coil. R28*		1					that the entire filter assembly be replaced
R11 3R77-P330K Composition: 33 ohms ±105, 1/2 w. R24 3R77-P103K Composition: 47,000 ohms ±105, 1/2 w. R25 3R77-P473K Composition: 47,000 ohms ±105, 1/2 w. R26 3R77-P512K Composition: 10,000 ohms ±105, 1/2 w. R27* 3R77-P512K Composition: 5100 ohms ±105, 1/2 w. R28 3R77-P512K Composition: 5100 ohms ±105, 1/2 w. Added by Rev B. R11 5490828-P30 Rod: 0.33 magchm ±105 res, 1 w max; sim to Globar Type 783H-3. CHANNEL GUARD INSTALLATION KIT 19A127174-G2 198204364-P2 Coil. R28 P33 R37-P304K Ray B. R29* 198201074-P304 Tap screw, 6-32 x 1/4. (4) R39 P30		1 1		- · · · · · · · · · · · · · · · · · · ·		:	attenuation.
R24 3R77-P103K Composition: 10,000 ohms ±10%, 1/2 w. R25 3R77-P473K Composition: 47,000 ohms ±10%, 1/2 w. Composition: 10,000 ohms ±10%, 1/2 w. R26 3R77-P103K Composition: 10,000 ohms ±10%, 1/2 w. R27* 3R77-P512K Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 5490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 5490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R72 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R72 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R71 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. R72 S490828-P30 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. L101 T488079-P8 Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. L102 L103 L19204814-P2 Coil. L103 L19204814-P2 Coil. L104 L19204814-P2 Coil. L105 L19204814-P2 Coil. L106 L19204834-P2 Coil. L107 L19204334-P2 Coil. L108 L19204334-P2 Coil. L109 L19204334-P2 Coil. L108 L19204334-P2 Coil. L109 L19204334-P2 Coil. L108 L19204334-P2 Coil. L108 L19204334		i l		, , , ,		ī	JACKS AND RECEPTACLES
R25 3877-P473K Composition: 47,000 ohms ±10%, 1/2 w. R27* 3877-P512K Composition: 10,000 ohms ±10%, 1/2 w. Added by Rev B. Composition: 5100 ohms ±10%, 1/2 w. Added by Rev B. Composition: 5100 ohms ±10%, 1/2 w. L101 7488079-P8 Choke, RF: 2.2 mh ±10%, 1 ohm DC res; sim to Jeffers 4411-12K. Coil. Coil. Coil. L103* 198204364-P2 Coil. L104* 198204364-P2 Coil. L105* 198204364-P2 Coil. Earlier than REV A: Coil. 198204384-91 Coil. 198204384-92 Coil. Earlier than REV A: Coil. 198204381-91 Coil. L106* 1982043918-02 Coil. L107 1982043918-02 Coil. L108 198204797-02 Coil. L109 198204797-02 Coil. L109 198204797-02 Coil. L109 198204797-02 Coil. L110 198204797-02 Coil. L111 198204797-02 Coil. L111 198204797-03 Coil. Coil		1		1	J101	19C303426-G1	
R26 3877-P103K Composition: 10,000 chas ±10%, 1/2 w. R27* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. Added by Rev B. R27* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. Added by Rev B. R27* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. Added by Rev B. R27* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. R28* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. Added by Rev B. R27* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. R28* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. R28* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. R28* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. R29* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. R20* 3877-P512K Composition: 5100 chas ±10%, 1/2 w. R20* 3877-P512K dill-12K. R20* 3877-		1		· '	J102	19B205689-G1	
R27* 3R77-P512K Composition: 5100 ohms 110%, 1/2 w. Added by Rev B. Li01 7488079-P8 Cohee, RF: 2.2 uh f10%, 1 ohm DC res; sim to Jeffers 4411-12K. RT1 5490828-P30 Rod: 0.33 megohm f10% res, 1 w max; sim to Globar Type 783H-3. CHANNEL GIARD INSTALLATION KIT 19A127174-02 Li05* 19B204364-P2 Coil. Earlier than REV A: Coil. Li05* 19B204364-P2 Coil. Earlier than REV A: Coil. Earlier than REV A: Coil. Earlier than REV A: Coil. 19B204364-P2 Coil. Earlier than REV A: Coil. Earlier than RE		1		· · · · · · · · · · · · · · · · · · ·			
RT1 5490828-P30 Rod: 0.33 megohn ±10% res, 1 w max; sim to Clobar Type 783H-3. CHANNEL GUARD INSTALLATION KIT 19A127174-02 L105* 19B204364-P2 Coil. Coil. Coil. Coil. L105* 19B204364-P2 Coil. L105* 19B204364-P5 L106* 19B204364-P5 L106* 19B204364-P5 L106* 19B204364-P5 L106* 19B204364-P5 L106* 19B204364-P5 L106* 19B204523-P1 Coil. L106* 19B204523-P1 Coil. L106* 19B204523-P1 Coil. L107 19B204523-P1 Coil. L108* 19B204523-P1 Coil. L109* 19B204523-P1 Coil. L109* 19B204718-G2 Coil. L110* 19B20479-G2 Coil. L110* 19B20479-G2 Coil. L110* 19B20479-G1 Coil. L110* 19B20479-G1 Coil. L111* 19B20479-G1 Coil. L112* T488079-P3* Choke, RF: 1.5 µh ±10%, 0.5 ohm DC res; sim to RMC Type JF Discap. L114* T488079-P8 Choke, RF: 2.2 µh ±10%, 1 ohm DC res; sim to AMP 42827-2. Contact, electrical; sim to AMP 42827-2. Contact, electrical; sim to AMP 42827-2. L114* T488079-P8 Choke, RF: 2.2 µh ±10%, 1 ohm DC res; sim to Term of the Core of 5494481-P7 Coramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. L114* T488079-P8 Contact, electrical; sim to AMP 42827-2.		R27*	3R77-P512K	, , , , , , , , , , , , , , , , , , , ,	7101	7400070 70	,
RT1 5490828-P30	_					(page)	Jeffers 4411-12K.
Collaboration Channel Guard Intervent Channel Guard Intervent Channel Guard Intervent Channel Guard Intervent Collaboration Channel Guard Intervent Collaboration Collaborat	- 1	P.771	5400020 720		1		
CHANNEL GIARD INSTALLATION KIT 198201074-P304 198201074-P304 198201074-P304 198201074-P304 198204364-G2 101. 106 198204523-P1 107 198204313-P1 108 198204718-G2 109 198204718-G2 109 198204718-G2 109 198204718-G1 109 198204797-G2 100 109 198204718-G2 100 109 198204797-G2 100 109 198204797-G2 100 109 198204718-G2 100 109 198204797-G2 100 109 198204718-G2 100 109 198204718-G2 100 109 198204797-G2 100 109 198204797-G2 100 109 198204718-G2 100 109 109 109 109 109 109 109 109 109		K11	5490828-P30		1		
198201074-P304 Tap screw, 6-32 x 1/4. (4) Li06 198204523-P1 Coil. Earlier than REV A: Coil. Earlier				CHANNOL CHADD INSTALLATION VIT		1 :	Earlier than REV A:
19B201074-P304 Tap screw, 6-32 x 1/4. (4) Li06 19B204523-P1 Coil. 19B205480-G2 Harness. Includes: Li07 19B204813-P1 Coil. 19B204718-G2 Coil. 19B204718-G2 Coil. 19B204718-G2 Coil. 19B204718-G1 Coil. 19B204718-G1 Coil. 19B204718-G1 Coil. 19B204718-G1 Coil. 19B204718-G1 Coil. 19B204718-G2 Coil. 19B204718-G1 Coil. 19B20479-G2 Coil. 19B20479-G3 Coil. 19B20479-G2 Coil. 19B20479-G3 Coil. 19B20479-G2 Coil. 19B20479-G2 Coil. 19B20479-G3 Coil. 19B20479-G2 Coil. 19B2479-G2 Coil. 19B2479-G2 Coil. 19B2479-G2 Coil. 19B24	-				L105*	19B204364-P5	
P130				MISCELLANEOUS		19B204364-G2	
P130 thru p135	-		19B201074-P304	Tap screw, 6-32 x 1/4. (4)	L106	19B204523-P1	Coil.
C102 and C103 C104 5496203-P446 Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -5600 PPM. C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 Ceramic disc:	- 1		19B205480-G2	Harness. Includes:	L107	19B204813-P1	Coil.
C102 and C103 C104 5496203-P446 Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -5600 PPM. C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C106 Type JF Discap. C107 C108 Type JF Discap. C109 198204718-G1 Coil. L110 19820479-G2 Coil. L111 19820479-G1 Coil. C101 Type JF Discap. C102 Type JF Discap. C103 C104 Type JF Discap. C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C106 Type JF Discap. C107 Type JF Discap. C108 Type JF Discap. C109 198204718-G1 Coil. C110 19820479-G2 Coil. C111 19820479-G2 Coil. C111 19820479-G2 Coil. C112 Type JF Discap. C113 Type JF Discap. C114 Type JF Discap. C115 Type JF Discap. C116 Type JF Discap. C117 Type JF Discap. C118 Type JF Discap. C118 Type JF Discap. C119 198204718-G1 Coil. C201. C201. C201. C201. C201. C201. C348079-P7 Choke, RF: 1.5 µh ±10%, 0.5 ohm DC res; sim to Jeffers 4411-10K. C348079-P8 Choke, RF: 2.2 µh ±10%, 1 ohm DC res; sim to Jeffers 4411-12K. C348079-P8 Choke, RF: 2.2 µh ±10%, 1 ohm DC res; sim to Jeffers 4411-12K. C348079-P8 Choke, RF: 2.2 µh ±10%, 1 ohm DC res; sim to Jeffers 4411-12K. C348079-P8 Choke, RF: 1.5 µh ±10%, 0.5 ohm DC res; sim to Jeffers 4411-12K. C348079-P8 Choke, RF: 1.5 µh ±10%, 0.5 ohm DC res; sim to Jeffers 4411-12K. C488079-P8 Choke, RF: 2.2 µh ±10%, 1 ohm DC res; sim to Jeffers 4411-12K. C348079-P8 Choke, RF: 1.5 µh ±10%, 0.5 ohm DC res; sim to Jeffers 4411-12K. C488079-P8 Choke, RF: 1.5 µh ±10%, 0.5 ohm DC res; sim to Jeffers 4411-12K. C105 Type JF Discap. C106 Type JF Discap. C107 Type JF Discap. C108 Type JF Discap. C109 Type JF Discap. C100 Type JF Discap. C101 Type JF Discap. C101 Type JF Discap. C101 Type JF Discap. C101 Type JF Discap. C1	- 1		4029840-P2	Contact, electrical; sim to Amp 42827-2.	L108	19B204718-G2	Coil.
Canada C					L109	19B204718-G1	Coil.
REV B C102							Coil.
C102 and C103 C104 5496203-P446 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to C105 C105 C105 C105 C105 C105 C105 C105							
- Clos S494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to and clos Clos S494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to and clos Cl	1				L112	7488079-P7	Choke, RF: 1.5 μh $\pm 10\%$, 0.5 ohm DC res; sim to Jeffers 4411-10K.
C104		and	5494481-P7	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.		:	to Jeffers 4412-7K.
C105 5494481-P7 Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. P101 4029840-P2 Contact, electrical; sim to Amp 42827-2.	-	1	5496203-P446	Ceramic disc: 180 pf ±5%, 500 VDCW, temp coef -5600 PPM.	L114	7488079-P8	Jeffers 4411-12K.
to Ame Type of Discap.		C105	5494481-P7	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim	p101	402984002	
				to KMC Type JF Discap.		i	
			•				

DESCRIPTION

SYMBOL | GE PART NO.

DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189-6.	P103 thru P106	4029840-P2	Contact, electrical; sim to Amp 42827-2.
Silver mica: 12 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to	P109 thru P113	4029840-P2	Contact, electrical; sim to Amp 42827-2.
RMC Type JF Discap.	P113	4029840-P1	Contact, electrical; sim to Amp 41854.
Variable: approx 2.53-12.78 pf, 1250 v peak; sim to Johnson 160-107-43.	Pl15 thru Pl18	4029840-P2	Contact, electrical; sim to Amp 42827-2.
Variable: approx 3-7 pf, 2100 v peak.	P119	4029840-Pl	Contact, electrical; sim to Amp 41854.
Refer to Mechanical Parts (RC-1628).	P1 20	4029840-P2	Contact, electrical; sim to Amp 42827-2.
Variable: 4-17 pf; sim to Teleradio T-9974.	thru Pl22		
Ceramic disc: 470 pf $\pm 20\%$, 1000 VDCW; sim to RMC Type JF Discap.	P123	4033513-P17	Contact, electrical; sim to Bead Chain R125-19.
Tubular: 2 pf ±0.1 pf, 500 VDCW, temp coef	P1 25	4029840-P1	Contact, electrical; sim to Amp 41854.
O PPM.	Pl 26 thru	4029840-P2	Contact, electrical; sim to Amp 42827-2.
Ceramic, feed-thru: .001 µf +100%-0%, 500 VDCW; sim to Allen Bradley Type FA5C.	P135		
			RESISTORS
Ceramic, feed thru: 680 pf ±20%, 1000 VDCW; sim to Sprague Type 544C.	R101	3R77-P683K	Composition: 68,000 ohms ±10%, 1/2 w.
	R102	3R77-P393K	Composition: 39,000 ohms ±10%, 1/2 w.
	R103	3R79-P333K	Composition: 33,000 ohms ±10%, 2 w.
LOW PASS FILTER ASSEMBLY 19D402233-G9	R104	3R77-P101K	Composition: 100 ohms ±10%, 1/2 w.
The low pass filter is factory tuned. If it is found to be defective it is recommended	R105 R106	3R77-P153K	Composition: 15,000 ohms ±10%, 1/2 w.
that the entire filter assembly be replaced to maintain rated power output and spurious	R105	3R77-P184K	Composition: 0.18 megohm ±10%, 1/2 w.
attenuation. Earlier than REV B:	R107	3R79-P333K 19Al15416-P7	Composition: 33,000 ohms ±10%, 2 w. Precision, wirewound: 3 ohms ±1%, 2 w; sim
Barrer than KBV B.	l KIOS	194115410-77	to Dale Type RS-2B.
LOW PASS FILTER ASSEMBLY 19D402233-G5			SWITCHES
The low pass filter is factory tuned. If it is found to be defective it is recommended that the entire filter assembly be replaced	S101	4031922-P1	Push: single pole, single throw, normally open, 1/2 amp at 12 VDC; sim to Stackpole Type SS-15.
to maintain rated power output and spurious attenuation.	S102	19B209040-P1	Slide: DPDT, 0.5 amp at 125 v; sim to Continental Wirt Type 126.
JACKS AND RECEPTACLES		ļ	
Connector: 20 pin contacts.	TB1	7487424-P2	Miniature, phen: 1 terminal.
Connector: 18 contacts.	TB2	7487424-P1	Miniature, phen: 1 terminal.
	твз	7775500-P16	Phen: 6 terminals.
Choke, RF: 2.2 µh ±10%, 1 ohm DC res; sim to Jeffers 4411-12K.	TB4	7487424- P 4	Miniature, phen: 2 terminals.
Coil.	Ì		
Coil.	V101		Type 8106.
Coil. Earlier than REV A:	V102		Type 8156.
Coil.	V103		Type 5894A.
Coil. Earlier than REV A:	İ		SOCKETS
Coil.	XV101	7480532-P11	Tube, mica-filled phen: 9 pins rated at 1 amp at 500 VRMS; sim to Elco 04-902-27.
Coil.	XV102	19C301007-P5	Tube, plastic: 12 pins rated at 5 amps max; sim to Alcon Metal Products 371G bottom mount.
Coil.	XV103	7489471-P3	Tube, ceramic or steatite: 7 pins.
Coil.			, octamize of Steatite. / pins.
Coil.			
Coil.	Z101	19B204543-G1	Coil. Includes tuning slug 5491798-P4.
Choke, RF: 1.5 μh $\pm 10\%$, 0.5 ohm DC res; sim to Jeffers 4411-10K.	C1	5496203-P468	Ceramic disc: 510 pf ±5%, 500 VDCW, temp coef -5600 PPM.

Z102

19B204543-G2

5496203-P468

19B200525-P9

Coil. Includes tuning slug 5491798-P4.

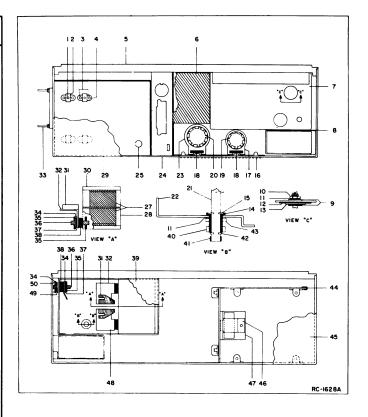
Rivet (Part of XY1-XY4).

Ceramic disc: 510 pf $\pm 5\%$, 500 VDCW, temp coef -5600 PPM.

MECHANICAL PARTS (SEE RC-1628)

PARTS LIST

SYMBOL	GE PART NO.	DESCRIPTION
2	4033089-P1	Clip (Part of XY1-XY4).
3	19A115793-P1	Contact, electrical; sim to Malco 2700. (Part of XY1-XY4).
4	19C311172-P2	Crystal socket. (Part of XY1-XY4).
5	19C303395-G4	Chassis heat sink.
6	19A121571-P1	Insulator.
7	19C3O3613-G1	Tuning chassis.
8	19A121527-P1	Plate.
9	7120754-P1	Fiber washer: sim to Mallory 203. (Used with Cll2 and Cll3).
10	7165075-P2	Hex nut: 3/8 - 32. (Used with C112).
11	7115130- P 9	Lockwasher; sim to Shakeproof 1220-2. (Part of post assembly and C112).
12	19A121516-P1	Teflon insulator. (Used with Cll2 and Cll3).
13	19Al 21520-Pl	Plate (Used with Cl12 and Cl13).
14	4031530-P1	Bearing: No. 32. (Part of post assembly).
15	4031532-P1	Cup washer. (Part of post assembly).
16	19C303599-P1	Heat sink.
17	19A121523-Pl	Heat sink. (Used with V101).
18	19B205622-P1	Spring. (Used with V101 and V102).
19	7165167- P 5	Tube shield insert; sim to Atlas 106-332-5. (Used with V101).
20	7165167-P9	Tube shield insert; sim to Atlas 106-332-5. (Used with V102).
	19A121189-P3	Post. (Part of post assembly).
22	19B204791-P1	Post assembly bracket. (Used with Cl14).
23	19A121523-P2	Heat sink. (Used with V102).
24	19B204395-G3	Chassis.
25 26	4036555-P1	Insulator, disc: nylon. (Used with Q8 on AlC All2, Al21-Al26). Not Used.
27	7165167-P3	Tube shield insert. (Used with V103).
28	19B204792-P1	Heat sink. (Used with V103).
29	19C303495-G8	Station top cover. (except Repeaters and VM).
	19C303673-G3	Station top cover. (Repeaters and VM only).
	19C303396-G1	Mobile top cover.
30	19B204793-P1	Heat sink. (Used with V103).
31	19Al 21529-P1	Contact. (Used with V103).
32	19B204435-P2	Plate line. (Used with V103).
33	19A121676-P1	Guide pin. (Used with J101).
34	5493361-P5	Spring washer; sim to Shakeproof 3502-10-58.
35	N509P608C13	Dowel pin, spring.
36	19A121465-P1	Post.
37	N 40 2P 39 C1 3	Washer.
38	19B204756-P1	Insulator, ceramic.
39	19C303605-P1	Tuning cover.
40	4031531-P1	Locknut: No. 32. (Part of post assembly).
41	4031527-P2	Collar. (Part of post assembly).
42	N910P18C13	Retaining ring. (Part of post assembly).
43	7893938-P1	Nut: no. 38. (Part of post assembly).
44	4029030-P10	Channel, rubber.
45	19C303495-G7	Station Bottom Cover.
l	19C303396-G3	Mobile Bottom Cover.
46	19A121065-P1	Support. (Used with FL1 and XFL1).
47	19A121257-G1	Angle. (Used with FL1 and XFL1).
48	19B204435-P1	Plate line. (Used with V103).
49	198204435-P1 198121547-P1	Plate line. (Used with V103). Plate.
50	19B204776-P1	Angle support.
	202201110-24	g suppos t.
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PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A thru C - (Exciter Board A101-A106 & A121-A126) REV. A thru D - (Exciter Board A107-A112)

Incorporated into initial shipment.

REV. A - (Channel Guard Low Pass Filter G101)

To improve operation. Changed Cl.

REV. B - (Channel Guard Low Pass Filter G101)

To reduce input to filter to prevent a square wave output. Added $\ensuremath{\mathtt{R27}}$.

REV. D - (Exciter Board A101-A106 & A121-A126)
REV. E - (Exciter Board A107-A112)

To improve stability and facilitate adjustment of modulation limiting and Channel Guard levels. Changed R12 and R34.

(Chassis & PA Assembly 19E500858-G1 & G2)

REV. A - To eliminate FM noise caused by mechanical vibration of the driver output and PA grid coils. Changed L104/L105.

REV. B - To improve performance of transmitter. Changed FL101.

REV. E - (Exciter Board A101-A106 & A121-A126)
REV. F - (Exciter Board A107-A112)

To facilitate manufacturing. Deleted the heat sink and mechanical parts to mount Q8. Added parts to mount Q8 on the

REV. A - (Channel Guard Encoder G102)

Incorporated into initial shipment.

PARTS LIST

PARTS LIST

LBI-3936D

CHANNEL GUARD ENCODER G102 4EH17A10 19C311802-G2

SYMBOL	GE PART NO.	DESCRIPTION
		CAPACITORS
C1*	19B209243-P103	Polyester: 0.022 µf ±10%, 50 VDCW. Earlier than REV A: Polyester: 0.015 µf ±20%, 50 VDCW.
C2	19B209243-P3	Polyester: 0.022 µf ±20%, 50 VDCW.
С3	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C4	19B209243-P9	Polyester: 0.22 µf ±20%, 50 VDCW.
C5	19 B2 09243-P8	Polyester: 0.15 µf ±20%, 50 VDCW.
C6	19B209243-P3	Polyester: 0.022 µf ±20%, 50 VDCW.
C7	5494481~P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C8	19B209243-P14	Polyester: 0.33 µf ±20%, 250 VDCW.
C9	5496267-P1	Tantalum: 6.8 µf ±20%, 6 VDCW; sim to Sprague Type 150D.
C10	19B209243-P117	Polyester: 0.22 µf ±10%, 50 VDCW.
Cll thru Cl3	5494481-P111	Ceramic disc: .001 µf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
		DIODES AND RECTIFIERS
CR1 and CR2	19A115250-P1	Silicon.
FL1		TONE FREQUENCY NETWORK 198205280
	199205280-G3 199205280-G4 199205280-G6 199205280-G6 199205280-G8 199205280-G9 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G1 199205280-G2 199205280-G2 199205280-G2 199205280-G2 199205280-G2 199205280-G2	82.5 Hz 94.8 Hz 100.0 Hz 103.5 Hz 1107.2 Hz 110.9 Hz 114.8 Hz 118.8 Hz 123.0 Hz 127.3 Hz 131.8 Hz 136.5 Hz 146.2 Hz 146.2 Hz 156.7 Hz 162.2 Hz 167.9 Hz 173.8 Hz 179.9 Hz 179.9 Hz 186.2 Hz 179.9 Hz 186.2 Hz 186.2 Hz
Jl thru J6	4033513-P4	JACKS AND RECEPTACLES
Q1 and Q2	19A115123-P1	TRANSISTORS
Q3 thru Q5	19A115362-P1	Silicon, NPN; sim to Type 2N2925.
1		RESISTORS
R1	3R77-P333K	Composition: 33,000 ohms ±10%, 1/2 w.
R2	3R77-P1 83K	Composition: 18,000 ohms ±10%, 1/2 w.

SYMBOL	GE PART NO.	DESCRIPTION
R3	3R77-P274K	Composition: 0.27 megohms ±10%, 1/2 w.
R4	3R77-P6 20J	Composition: 62 ohms ±5%, 1/2 w.
R5	3R77-P822K	Composition: 8200 ohms ±10%, 1/2 w.
R6	3R77-P153K	Composition: 15,000 ohms ±10%, 1/2 w.
R7	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
R8	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R9	3R77-P184K	Composition: 0.18 megohms ±10%, 1/2 w.
R10	3R77-P622J	Composition: 6200 ohms 15%, 1/2 w.
R11	3R77-P330K	Composition: 33 ohms ±10%, 1/2 w.
R12	5495948-P365	Deposited carbon: $46,400$ ohms $\pm 1\%$, $1/2$ w; sim to Texas Instrument CD1/2MR.
R13	3R77-P682J	Composition: 6800 ohms ±5%, 1/2 w.
R14	3R77-P244J	Composition: 0.24 megohms ±5%, 1/2 w.
R15	19A116278-P233	Metal film: 2150 ohms ±2%, 1/2 w.
R16	19A116278-P301	Metal film: 10,000 ohms ±2%, 1/2 w.
R17	19A116278-P65	Metal film: 46.4 ohms ±2%, 1/2 w.
R18	19A116278-P329	Metal film: 19,600 ohms ±2%, 1/2 w.
R19	19A116278-P285	Metal film: 7500 ohms ±2%, 1/2 w.
R20	19A116278-P412	Metal film: 130,000 ohms ±2%, 1/2 w.
R21	19A116278-P269	Metal film: 5110 ohms ±2%, 1/2 w.
R22	19A116278-P117	Metal film: 147 ohms ±2%, 1/2 w.
R23	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
RT1	5490828-P30	Thermistor: 330,000 ohms ±10%, color code black and gray; sim to Globar Type 783H-3.
RT2	5490828-P36	Thermistor: 55,000 ohms ±10%, color code black and red; sim to Globar Type 723B.
W1		(Part of XFL1),
XPL1	19A121920-G3	Reed, mica-filled phen: 7 pins rated at 1 amp at 500 VRMS with 4-1/4 inches of cable.
		ENCODER INSTALLATION KIT 19A127174-G1
		miscellaneous
	N404P13C13	Lockwasher, no. 6.
	N 80 P1 3005 C1 3	Machine screw, no. 6-32 x 5/16.
1	19B201074-P304	Tap screw, no. 6-32 x 1/4.
	N210P13C13	Nut, no. 6-32.
	19B205480-G2	Harness. Includes:
P130 thru	4029840-P2	Contact, electrical; sim to Amp 42827-2.
P135		
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*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

ORDERING SERVICE PARTS

Each component appearing on the schematic diagram is identified by a symbol number, to simplify locating it in the parts list. Each component is listed by symbol number, followed by its description and GE Part Number.

Service Parts may be obtained from Authorized GE Communication Equipment Service Stations or through any GE Radio Communication Equipment Sales Office. When ordering a part, be sure to give:

- 1. GE Part Number for component
- Description of part
 Model number of equipment
- 4. Revision letter stamped on unit

These instructions do not purport to cover all details or variations in equipment nor to provide for every possible contingency to be met in connection with installation, operation or maintenance.

Should further information be desired, or should particular problems arise which are not covered sufficiently for the purchaser's purposes, contact the nearest Radio Communication Equipment Sales Office of the General Electric Company.

MAINTENANCE MANUAL

LBI-3868



MOBILE RADIO DEPARTMENT LYNCHBURG, VIRGINIA 24502 CABLE GECOMPROD (In Canada, Canadian General Electric Company, Ltd., 100 Wingold Avenue, Toronto 19, Ontario)